

SM6HT

High temperature Transil[™] for automotive applications

Features

- High performance TRANSIL designed to fit high temperature environment like automotive applications
- High reliability planar technology
- High performance in voltage regulation mode
- Very low leakage current:
- I_R max. = 5 μA @ T_{amb} = 150° C
- Peak pulse power: 600 W (10/1000 µs)
- Fast response time
- Unidirectional type
- Low clamping factor

Description

This high performance Transil series has been designed to fit high temperature environment such as automotive applications, using surface mount technology.

These devices are using high reliability planar technology resulting in high performances in voltage regulation mode and low leakage current at high temperature.



Order codes

Part number	Marking
SM6HT24A	EMB
SM6HT27A	EPB
SM6HT30A	ERB
SM6HT36A	EVB
SM6HT39A	EXB
SM6HT43A	EYB

TM: TRANSIL is a trademark of STMicroelectronics

1 Characteristics

Table 1. Absolute maximum rating ($T_{amb} = 25^{\circ} C$)

Symbol	Parameter	Value	Unit	
P _{PP}	Peak pulse power dissipation ⁽¹⁾ T_j initial = T_{amb}		600	W
Р	Power dissipation on infinite heatsink	6	W	
I _{FSM}	Non repetitive surge peak forward current for unidirectional types	75	A	
T _{stg /} T _j	Storage and operating junction temperature range	-65 to 175	°C	
ΤL	Maximum lead temperature for soldering during 10 s.	260	°C	

1. for a surge greater than the maximum values, the diode will fail in short circuit.

Table 2. Thermal resistances

Symbol	Parameter	Value	Unit
R _{th(j-l)}	Junction to leads	20	°C/W
R _{th(j-a)}	Junction to ambient on printed circuit on recommended pad layout	100	°C/W

Table 3. Electrical characteristics ($T_{amb} = 25^{\circ} C$)

SymbolParameter V_{RM} Stand-off voltage V_{BR} Breakdown voltage V_{CL} Clamping voltage I_{RM} Leakage current I_{PP} Peak pulse current I_{PP} Peak pulse current V_{F} Forward voltage drop $V_{F} < 3.5 V @ I_{F} = 50 A$ (pulse test: $t_{p} \le 500 \ \mu$ s) I_{Z} Continuous regulation current		(unb	
V_{RM} Stand-off Voltage V_{BR} Breakdown voltage V_{CL} Clamping voltage I_{RM} Leakage current I_{PP} Peak pulse current V_F Forward voltage drop $V_F < 3.5 V @ I_F = 50 A$ (pulse test: $t_p \le 500 \ \mu s$)	Symbol	Parameter	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	V _{RM}	Stand-off voltage	IF ····
$\begin{tabular}{ c c c c c } \hline I_{RM} & Leakage current \\ \hline I_{PP} & Peak pulse current \\ \hline V_F & V_F < 3.5 V @ I_F = 50 A \\ (pulse test: t_p \le 500 \ \mu s) \\ \hline I_{PP} & I_{PP} \\ \hline I_{RM} & I_{PP} \\ \hline I_{PP} & I_{PP} \\ \hline I_{PP$	V _{BR}	Breakdown voltage	
$\begin{tabular}{ c c c c c } \hline I_{RM} & Leakage current & & & & & & & & & & & & & & & & & & &$	V _{CL}	Clamping voltage	
$V_{F} = \begin{cases} Forward voltage drop \\ V_{F} < 3.5 V @ I_{F} = 50 A \\ (pulse test: t_{p} \le 500 \ \mu s) \end{cases}$	I _{RM}	Leakage current	
$V_{F} \qquad V_{F} < 3.5 V @ I_{F} = 50 A$ (pulse test: $t_{p} \le 500 \ \mu$ s)	I _{PP}	Peak pulse current	IRM
	V _F	V _F < 3.5 V @ I _F = 50 A	
	Ι _Ζ	Continuous regulation current	IPP
			-

		, d'	I _{RM} @ V _{BR}			V _{BR} @	ፆ I _R ⁽¹⁾		V _{CL}	@ I _{PP}	α Τ ⁽²⁾	I _Z @		
Types	Marking	T _{amb} =25° C	T _{amb} =150° C						10/10	00 µs		T _{amb} =50°C		
	.0.	max	max		min	nom	max		max		max	max		
10		μA	μA	V	V	V	V	mA	V	А	10 ⁻⁴ /°C	mA		
SM6HT24A	EMB		5	20.5	22.8	24	25.2		33.2	18.0	9.4	50		
SM6HT27A	EPB				23.1	25.7	27	28.4		37.5	16.0	9.6	44	
SM6HT30A	ERB	2		25.6	28.5	30	31.5	4	41.5	14.5	9.7	40		
SM6HT36A	EVB	2		30.8	34.2	36	37.8	I	49.9	12.0	9.9	33		
SM6HT39A	EXB						33.3	37.1	39	41.0		53.9	11.1	10.0
SM6HT43A	EYB			36.8	40.9	43	45.2		59.3	10.1	10.1	28		

1. Pulse test: t_p < 50 ms

2. $\Delta V_{BR} = \alpha T x (T_{amb} - 25) x V_{BR} (25^{\circ} C)$

Figure 1. Peak power dissipation versus initial junction temperature



50







Tamb(°C)

100

125

150

175

75



Figure 5. Junction capacitance versus reverse applied voltage (typical values)

Figure 6. Peak forward voltage drop versus peak forward current (typical values)



%

110

57

Figure 7. Variation of thermal impedance junction to ambient versus pulse duration (Printed circuit board FR4 with recommended pad layout)





Figure 9. Variation of leakage current versus junction temperature (typical values)





2 Order information scheme

	SM 6 HT 43 A Surface Mount
	Peak Pulse Power 6 = 600 W
	High Temperature Breakdown voltage
	A = Unidirectional
	A - Onidirectional
	orodule
	eteri
	05016°
	Ob Ob
	, ict(S)
	orodu.
lete	
0105015	



3 Package information

- Case: JEDEC DO-214AA molded plastic over Planar junction
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: For unidirectional types the band indicates cathode.
- Flammability: Epoxy is rated UL94V-0
- RoHS package

Table 4. SMB dimensions



Figure 10. SMB footprint dimensions

Figure 11. Marking information





Ordering information 4

Part number	Marking	Package	Weight	Base qty	Delivery mode	
SM6HT24A	EMB					
SM6HT27A	EPB	SMB				
SM6HT30A	ERB		CMD	0.10 a	5000	Topo and roal
SM6HT36A	EVB		0.12 g	5000	Tape and reel	
SM6HT39A	EXB					
SM6HT43A	EYB					

Revision history 5

Revision history					
Date	Revision	Changes			
Apr-1999	4A	Last release.			
26-Jan-2005	5	Figure 9 on page 4: leakage current improved.			
18-Mar-2005	6	Table 3: Electrical characteristics ($T_{amb} = 25^{\circ}$ C) on page 2: V_{F} specification added.			
21-Mar-2007	7	Table 1 on page 2: Power dissipation upgraded from 5 W to 6 W.Table 3 on page 2: Iz max parameter added.Figure 2 on page 3: Updated for 6 W power dissipation.			

Figur Figur obsolete Production



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2007 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

